

DATE: 13/06/2017

ADVERTISEMENT

Applications are invited for filling up the following post under the project entitled: **Development of Highly Sensitive Photo-detector based on “Dielectrophoretic Assembly of TiS₃ Nanoribbons”** sponsored by Science and Engineering Research Board(SERB), DST, Govt. of India. **The project duration is 03(three) years.**

Name & No. of post

1. Junior Research Fellow (JRF) (01)

MINIMUM QUALIFICATIONS & REMUNERATIONS:

M. Tech. in Nanoscience and Nanotechnology, Optoelectronics, Electronics and communication & Material science with 60% marks or equivalent CGPA.

or

M.Sc. with NET qualification in Electronics, Physics, Chemistry, Nanoscience, Nanotechnology with 60% marks or equivalent CGPA.

Remuneration: As per Govt. rules.

Desirable Qualifications:

Preference will be given to those candidates having at 06 months research experience on 2D materials and dielectrophoretic depositions.

Candidate(s) possessing the requisite qualifications send their applications through email(pmishra@jmi.ac.in) to the Principal Investigator by **03rd August, 2017** giving complete bio-data (with e-mail address and mobile no.)



Dr. Prabhash Mishra,
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